



AM50-0011 V6

#### **Features**

- Ideal for Base Station Applications
- High Gain: 17 dB @ 900 MHz
- Low Noise Figure: ≤1.0 dB @ 900 MHz
- Single Supply +5 VDC

#### **Description**

M/A-COM's AM50-0011 is a high dynamic range, GaAs MMIC, low noise amplifier in a low-cost SOT-26 package. It employs external matching to obtain optimum noise figure and intercept performance. The AM50-0011 may be operated with supply voltages of +5 V.

The AM50-0011 is ideally suited for use where low noise figure, high gain, and high dynamic range are required. Typical applications included receiver front ends in AMPS, GSM and ETACS base stations. It may also be used as an IF amplifier in certain other communication systems.

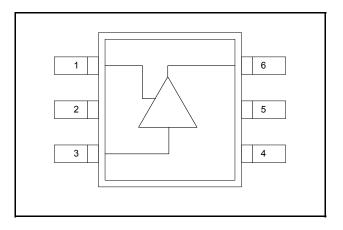
The AM50-0011 is fabricated using a low-cost 0.5-micron gate E-D SAGFET GaAs process. This process features full passivation for increased reliability. The AM50-0011 is 100% RF tested to ensure performance specification compliance.

# **Ordering Information**

Part Number	Package		
AM50-0011	Bulk Packaging		
AM50-0011TR	1000 piece reel		
AM50-0011TR-3000	3000 piece reel		
AM50-0011SMB	Sample Test Board		

Note: Reference Application Note M513 for reel size information.

### **Functional Block Diagram**



# **Pin Configuration**

Pin No.	Function	Pin No.	Function
1	VB	4	GND
2	GND	5	GND
3	RF IN	6	RF OUT

# Absolute Maximum Ratings <sup>1</sup>

Parameter	Absolute Maximum		
Supply Voltage	6 V		
RF input Power	8 dBm		
Operating Temperature	-40°C to +85°C		
Storage Temperature	-65°C to +150°C		

1. Exceeding any one or combination of these limits may cause permanent damage to this device.

<sup>•</sup> Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298



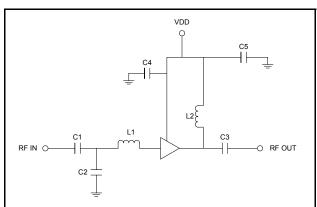
AM50-0011 V6

# Electrical Specifications: $T_A$ = 25°C, $Z_0$ = 50 $\Omega$ , F = 900 MHz, PIN = -20 dBm, Supply Voltage = 5V $^2$

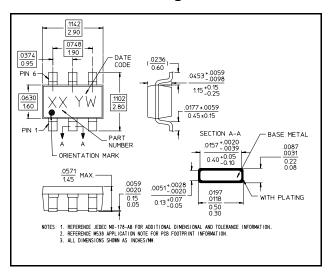
Parameter	Test Conditions Ur		Min	Тур	Max
Gain	800 - 1000 MHz	800 - 1000 MHz dB 15.8		16.8	17.8
Noise Figure	800 - 1000 MHz	800 - 1000 MHz dB		0.95	1.3
Output P1 dB	800 - 1000 MHz dBm		_	14	_
Input IP3	800 - 1000 MHz	dBm	_	13.5	_
Input VSWR	800 - 1000 MHz	_	_	1.5	_
Output VSWR	800 - 1000 MHz	_	_	1.7	_
Supply Current	800 - 1000 MHz	mA	_	40	60

<sup>2.</sup> All measurements are taken into a 50 Ohm system unless otherwise specified.

# **Application Schematic**



### **SOT-26 Plastic Package**



#### **Component List**

Part	Value	Case Size	Manufacturer
L1	6.8 nH	0402	Coilcraft
L2	68 nH	0402	Coilcraft
C1	1000 pF	0402	Murata
C2	3.9 pF	0402	Murata
C3	100 pF	0402	Murata
C4, C5	0.1 μF	0402	Murata

#### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

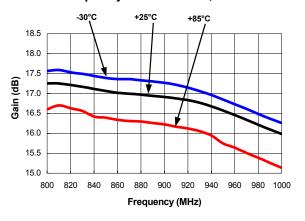
\_\_\_\_



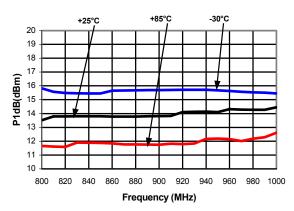
AM50-0011 V6

# **Typical Performance Curves**

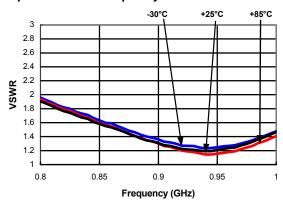
#### Gain vs. Frequency Pin = -20 dBm, Vdd = 5.0 Volts



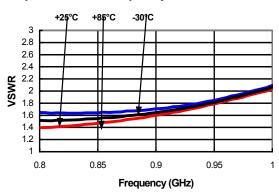
#### P1 dB vs. Frequency Vdd = 5 V



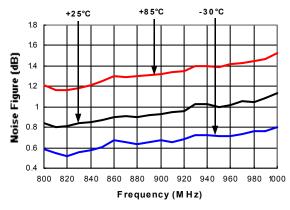
#### Input VSWR vs. Frequency



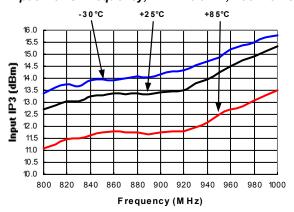
Output VSWR vs. Frequency



#### Noise Figure vs. Frequency



Input IP3 vs. Frequency, Pin = 20 dBm, Vdd = 5 Volts



- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

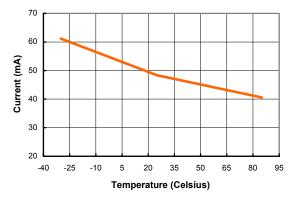




AM50-0011 V6

# **Typical Performance Curves**

#### Current vs. Temperature



<sup>•</sup> Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298